

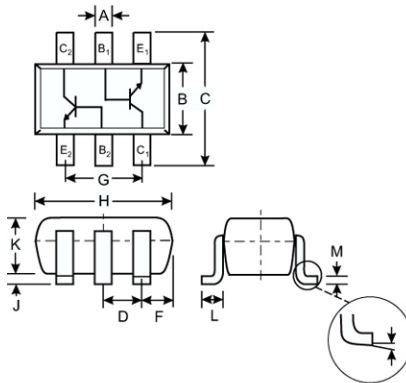
BC847BS

● **Features**

Ideally Suited for Automatic Insertion
 For Switching and AF Amplifier Applications
 Ultra-Small Surface Mount Package

● **Mechanical Data**

Case: SOT-363, Molded Plastic
 Case material - UL Flammability Rating
 Classification 94V - 0
 Moisture sensitivity: Level 1 per J-STD-020A
 Terminals: Solderable per MIL-STD-202,
 Method 208
 Terminal Connections: See Diagram
 Marking: K1F (See Page 2)
 Weight: 0.006 grams
 Ordering & Date Code Information: See Page 2



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
α	°8	
All Dimensions in mm		

● **Maximum Ratings** @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current	I _C	100	mA
Peak Collector Current	I _{CM}	200	mA
Peak Base Current	I _{BM}	200	mA
Power Dissipation (Note 1)	P _d	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	R _{θJA}	500	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +125	°C

● **Electrical Characteristics** @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
DC Current Gain (Note 2)	h_{FE}	200	—	450	—	$V_{CE} = 5.0\text{V}$, $I_C = 2.0\text{mA}$
Collector-Emitter Saturation Voltage (Note 2)	$V_{CE(SAT)}$	—	—	100 400	mV	$I_C = 10\text{mA}$, $I_B = 0.5\text{mA}$ $I_C = 100\text{mA}$, $I_B = 5.0\text{mA}$
Base-Emitter Saturation Voltage (Note 2)	$V_{BE(SAT)}$	—	755	—	mV	$I_C = 10\text{mA}$, $I_B = 0.5\text{mA}$
Base-Emitter Voltage (Note 2)	V_{BE}	580	665	700	mV	$V_{CE} = 5.0\text{V}$, $I_C = 2.0\text{mA}$
Collector Cutoff Current (Note 2)	I_{CBO} I_{CBO}	—	—	15 5.0	nA μA	$V_{CB} = 30\text{V}$, $I_E = 0$ $V_{CB} = 30\text{V}$, $T_j = 125^\circ\text{C}$
Emitter Cutoff Current (Note 2)	I_{EBO}	—	—	100	nA	$V_{EB} = 5.0\text{V}$, $I_C = 0$
Gain Bandwidth Product	f_T	100	—	—	MHz	$V_{CE} = 5.0\text{V}$, $I_C = 10\text{mA}$, $f = 100\text{MHz}$
Collector-Base Capacitance	C_{CBO}	—	—	1.5	pF	$V_{CB} = 10\text{V}$, $f = 1.0\text{MHz}$
Emitter-Base Capacitance	C_{EBO}	—	11	—	pF	$V_{EB} = 0.5\text{V}$, $f = 1.0\text{MHz}$

BC847BS

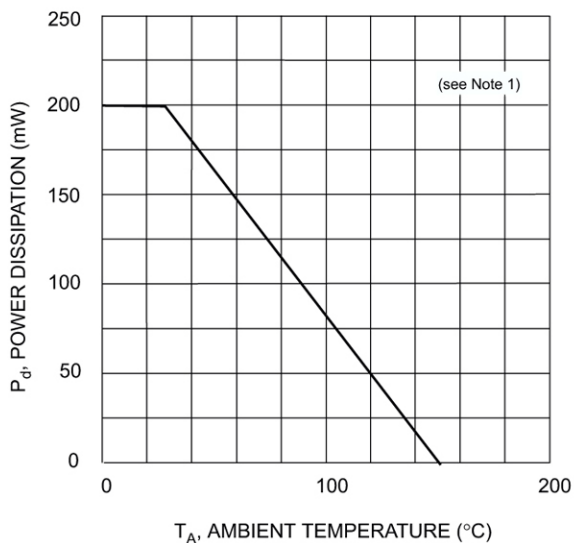


Fig. 1, Power Derating Curve

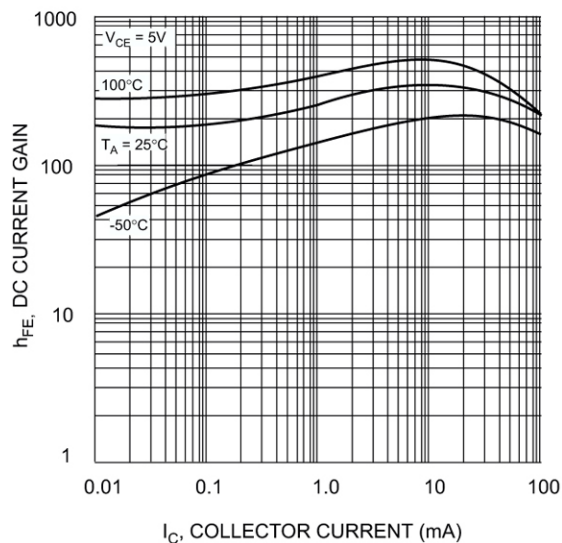


Fig. 2, DC Current Gain vs Collector Current

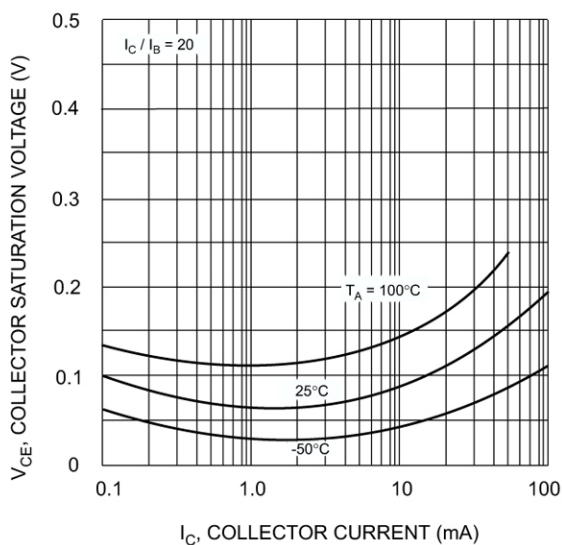


Fig. 3, Collector Saturation Voltage vs Collector Current

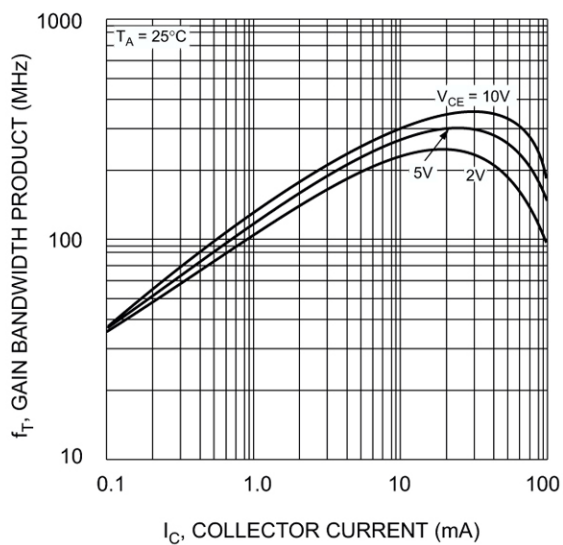


Fig. 4, Gain Bandwidth Product vs Collector Current

Notes: 1. Device mounted on FR4 printed circuit board.